Zener Diode

DZ3X120D0L

Panasonic

DZ3X120D0L

Silicon epitaxial planar type

For surge absorption circuit

■ Features

- Excellent rising characteristics of zener current Iz
- Low zener operating resistance Rz
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol:05

Packaging

Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Total power dissipation *1	PT	200	mW
Electrostatic discharge *2	ESD	±10	kV
Junction temperature	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C

Note) *1: Mounted on glass epoxy print board. (45 mm x 45 mm x 1 mm) (2 Diode total)

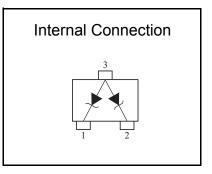
Solder in (1.0 mm x 1.0 mm)

*2: Test method:IEC61000 4 2(C = 150 pF,R = 330 Ω , Contact discharge:10 times)

Unit: mm 2.9 0.4 (0.95)(0.95)1. 9

- 1. Cathode1
- 2. Cathode2
- 3. Anode1,2

Panasonic	Mini3-G3-B		
JEITA	SC-59A		
Code	TO-236AA/SOT-23		



■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	11.4		12.6	V
Zener operating resistance	RZ	IZ = 5 mA			30	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			80	Ω
Reverse current	IR	VR = 9 V			0.05	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		8.5		mV/°C

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

- 2. *1: The temperature must be controlled 25°C for VZ mesurement. VZ value measured at other temperature must be adjusted to VZ (25°C)
 - *2: VZ guaranted 20 ms after current flow.
 - *3: Tj = 25°C to 150°C

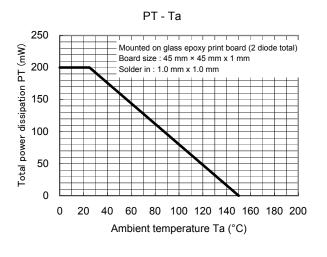
Established: 2010-08-05 : 2013-10-28 Revised

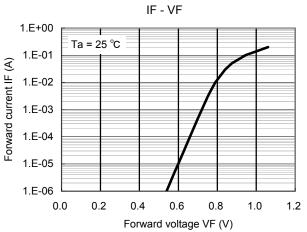
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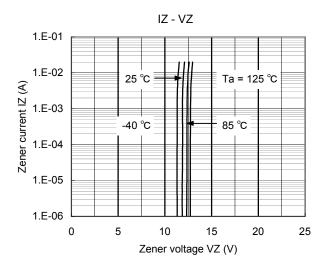
Zener Diode

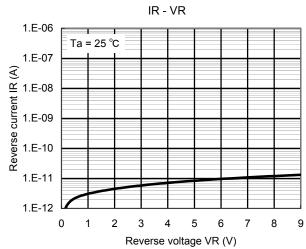
DZ3X120D0L

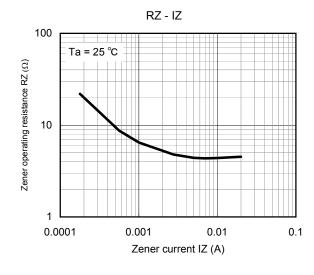
Technical Data (reference)

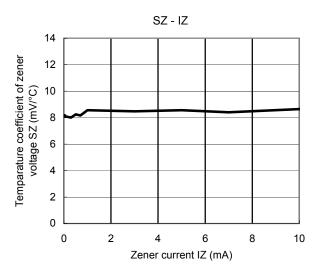












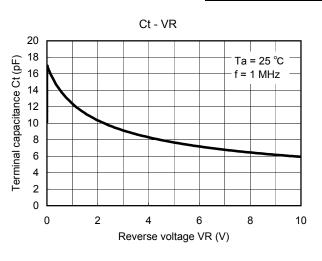
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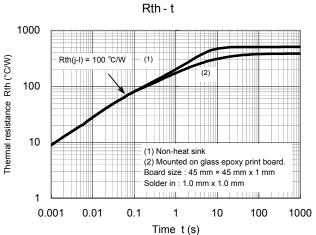
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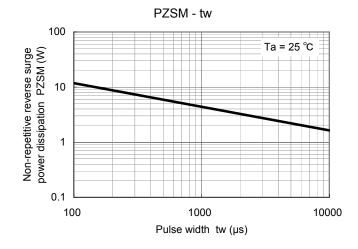
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Technical Data (reference)







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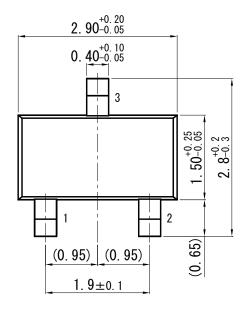
Zener Diode

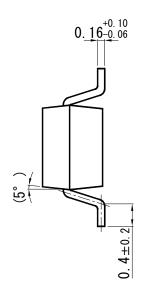
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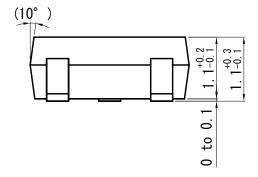
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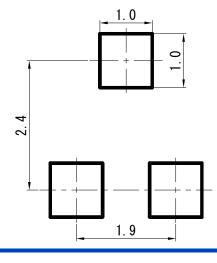
Unit: mm







■ Land Pattern (Reference) (Unit: mm)



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